

COMLINEAR[®] CLC1050, CLC2050, CLC4050

Low Power, 3V to 36V, Single, Dual, Quad Amplifiers

COMLINEAR CLC1050, CLC2050, CLC4050 Low Power, 3V to 36V, Single, Dual, Quad Amplifiers Rev 1A

FEATURES

- Unity gain stable
- 100dB voltage gain
- 550kHz unity gain bandwidth
- 0.5mA supply current
- 20nA input bias current
- 2mV input offset voltage
- 3V to 36V single supply voltage range
- ±1.5V to ±18V dual supply voltage range
- Input common mode voltage range includes ground
- 0V to $V_S - 1.5V$ output voltage swing
- CLC2050: improved replacement for industry standard LM358
- CLC4050: Improved replacement for industry standard LM324
- CLC1050: Pb-free SOT23-5
- CLC2050: Pb-free SOIC-8
- CLC4050: Pb-free SOIC-14

APPLICATIONS

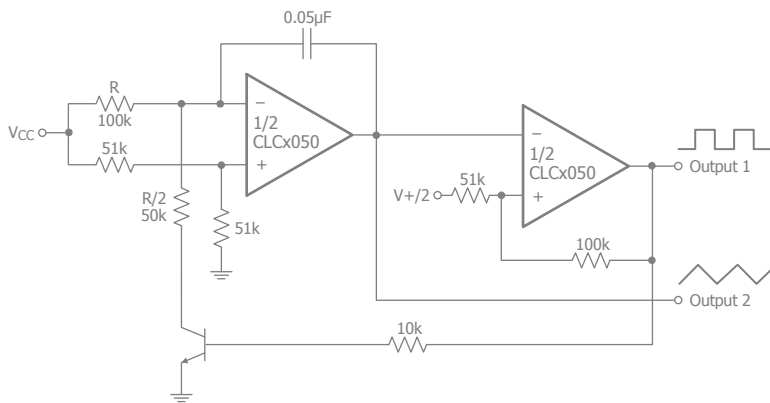
- Battery Charger
- Active Filters
- Transducer amplifiers
- General purpose controllers
- General purpose instruments

General Description

The COMLINEAR CLC1050 (single), CLC2050 (dual), and CLC4050 (quad) are voltage feedback amplifiers that are internally frequency compensated to provide unity gain stability. At unity gain ($G=1$), these amplifiers offer 550kHz of bandwidth. They consume only 0.5mA of supply current over the entire power supply operating range. The CLC1050, CLC2050, and CLC4050 are specifically designed to operate from single or dual supply voltages.

The COMLINEAR CLC1050, CLC2050, and CLC4050 offer a common mode voltage range that includes ground and a wide output voltage swing. The combination of low-power, high supply voltage range, and low supply current make these amplifiers well suited for many general purpose applications and as alternatives to several industry standard amplifiers on the market today.

Typical Application - Voltage Controlled Oscillator (VCO)



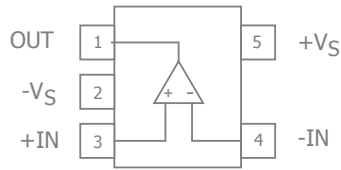
Ordering Information

Part Number	Package	Pb-Free	RoHS Compliant	Operating Temperature Range	Packaging Method
CLC1050IST5X	SOT23-5	Yes	Yes	-40°C to +85°C	Reel
CLC2050ISO8X	SOIC-8	Yes	Yes	-40°C to +85°C	Reel
CLC4050ISO14X	SOIC-14	Yes	Yes	-40°C to +85°C	Reel

Moisture sensitivity level for all parts is MSL-1.



CLC1050 Pin Configuration



CLC1050 Pin Assignments

Pin No.	Pin Name	Description
1	OUT	Output
2	-VS	Negative supply
3	+IN	Positive input
4	-IN	Negative input
5	+VS	Positive supply

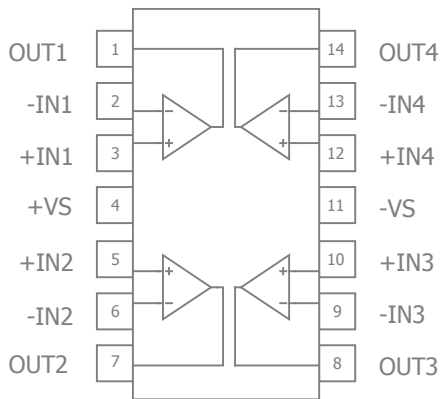
CLC2050 Pin Configuration



CLC2050 Pin Configuration

Pin No.	Pin Name	Description
1	OUT1	Output, channel 1
2	-IN1	Negative input, channel 1
3	+IN1	Positive input, channel 1
4	-VS	Negative supply
5	+IN2	Positive input, channel 2
6	-IN2	Negative input, channel 2
7	OUT2	Output, channel 2
8	+VS	Positive supply

CLC4050 Pin Configuration



CLC4050 Pin Configuration

Pin No.	Pin Name	Description
1	OUT1	Output, channel 1
2	-IN1	Negative input, channel 1
3	+IN1	Positive input, channel 1
4	+VS	Positive supply
5	+IN2	Positive input, channel 2
6	-IN2	Negative input, channel 2
7	OUT2	Output, channel 2
8	OUT3	Output, channel 3
9	-IN3	Negative input, channel 3
10	+IN3	Positive input, channel 3
11	-VS	Negative supply
12	+IN4	Positive input, channel 4
13	-IN4	Negative input, channel 4
14	OUT4	Output, channel 4



Absolute Maximum Ratings

The safety of the device is not guaranteed when it is operated above the "Absolute Maximum Ratings". The device should not be operated at these "absolute" limits. Adhere to the "Recommended Operating Conditions" for proper device function. The information contained in the Electrical Characteristics tables and Typical Performance plots reflect the operating conditions noted on the tables and plots.

Parameter	Min	Max	Unit
Supply Voltage	0	40	V
Differential Input Voltage		40	V
Input Voltage	-0.3	40	V
Power Dissipation ($T_A = 25^\circ\text{C}$) - SOIC-8		550	mW
Power Dissipation ($T_A = 25^\circ\text{C}$) - SOIC-14		800	mW

Reliability Information

Parameter	Min	Typ	Max	Unit
Junction Temperature			150	$^\circ\text{C}$
Storage Temperature Range	-65		150	$^\circ\text{C}$
Lead Temperature (Soldering, 10s)			260	$^\circ\text{C}$
Package Thermal Resistance				
SOT23-5		221		$^\circ\text{C}/\text{W}$
SOIC-8		100		$^\circ\text{C}/\text{W}$
SOIC-14		88		$^\circ\text{C}/\text{W}$

Notes:

Package thermal resistance (θ_{JA}), JEDEC standard, multi-layer test boards, still air.

Recommended Operating Conditions

Parameter	Min	Typ	Max	Unit
Operating Temperature Range	-40		+85	$^\circ\text{C}$
Supply Voltage Range	3 (± 1.5)		36 (± 18)	V



Electrical Characteristics

$T_A = 25^\circ\text{C}$ (if **bold**, $T_A = -40$ to $+85^\circ\text{C}$), $V_S = +5\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$ to $V_S/2$, $G = 2$; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Frequency Domain Response						
UGBW _{SS}	Unity Gain Bandwidth	$G = +1, V_{\text{OUT}} = 0.2V_{\text{pp}}, V_S = 5\text{V}$		330		kHz
		$G = +1, V_{\text{OUT}} = 0.2V_{\text{pp}}, V_S = 30\text{V}$		550		kHz
BW _{SS}	-3dB Bandwidth	$G = +2, V_{\text{OUT}} = 0.2V_{\text{pp}}, V_S = 5\text{V}$		300		kHz
		$G = +1, V_{\text{OUT}} = 0.2V_{\text{pp}}, V_S = 30\text{V}$		422		kHz
BW _{LS}	Large Signal Bandwidth	$G = +2, V_{\text{OUT}} = 1V_{\text{pp}}, V_S = 5\text{V}$		107		kHz
		$G = +2, V_{\text{OUT}} = 2V_{\text{pp}}, V_S = 30\text{V}$		76		kHz
Time Domain Response						
t_r, t_f	Rise and Fall Time	$V_{\text{OUT}} = 1\text{V}$ step; (10% to 90%), $V_S = 5\text{V}$		4		μs
		$V_{\text{OUT}} = 2\text{V}$ step; (10% to 90%), $V_S = 30\text{V}$		5.6		μs
OS	Overshoot	$V_{\text{OUT}} = 0.2\text{V}$ step		1		%
SR	Slew Rate	1V step, $V_S = 5\text{V}$		200		V/ms
		4V step, $V_S = 30\text{V}$		285		V/ms
Distortion/Noise Response						
THD	Total Harmonic Distortion	$V_{\text{OUT}} = 2V_{\text{pp}}, f = 1\text{kHz}, G = 20\text{dB}, C_L = 100\text{pF}, V_S = 30\text{V}$		0.015		%
e_n	Input Voltage Noise	$> 10\text{kHz}, V_S = 5\text{V}$		45		nV/ $\sqrt{\text{Hz}}$
		$> 10\text{kHz}, V_S = 30\text{V}$		40		nV/ $\sqrt{\text{Hz}}$
X_{TALK}	Crosstalk	Channel-to-channel, 1kHz to 20kHz		120		dB
DC Performance						
V_{IO}	Input Offset Voltage ⁽¹⁾	$V_{\text{OUT}} = 1.4\text{V}, R_S = 0\Omega, V_S = 5\text{V}$ to 30V		2	5	mV
					7	mV
dV_{IO}	Average Drift			7		$\mu\text{V}/^\circ\text{C}$
I_b	Input Bias Current ⁽¹⁾	$V_{\text{CM}} = 0\text{V}$		20	100	nA
					200	nA
I_{OS}	Input Offset Current ⁽¹⁾	$V_{\text{CM}} = 0\text{V}$		5	30	nA
					100	nA
PSRR	Power Supply Rejection Ratio ⁽¹⁾	DC, $V_S = 5\text{V}$ to 30V	70	100		dB
			60			dB
A_{OL}	Open-Loop Gain ⁽¹⁾	$+V_S = 15\text{V}, R_L = \geq 2\text{k}\Omega, V_{\text{OUT}} = 1\text{V}$ to 11V	85	100		dB
			80			dB
I_S	Supply Current, CLC1050 ⁽¹⁾	$R_L = \infty, V_S = 30\text{V}$		0.65	1.5	mA
		$R_L = \infty, V_S = 5\text{V}$		0.45	1.0	mA
	Supply Current, CLC2050 ⁽¹⁾	$R_L = \infty, V_S = 30\text{V}$		0.7	2.0	mA
		$R_L = \infty, V_S = 5\text{V}$		0.5	1.2	mA
	Supply Current, CLC4050 ⁽¹⁾	$R_L = \infty, V_S = 30\text{V}$		1.0	3.0	mA
		$R_L = \infty, V_S = 5\text{V}$		0.7	1.2	mA
Input Characteristics						
CMIR	Common Mode Input Range ^(1,3)	$+V_S = 30\text{V}$	0		$+V_S - 1.5$	V
CMRR	Common Mode Rejection Ratio ⁽¹⁾	DC, $V_{\text{CM}} = 0\text{V}$ to $(+V_S - 1.5\text{V})$	60	70		dB
			60			dB
Output Characteristics						
V_{OH}	Output Voltage Swing, High ⁽¹⁾	$+V_S = 30\text{V}, R_L = 2\text{k}\Omega$	26			V
			26			V
		$+V_S = 30\text{V}, R_L = 10\text{k}\Omega$	27	28		V
			27			V



Electrical Characteristics continued

$T_A = 25^\circ\text{C}$ (if **bold**, $T_A = -40$ to $+85^\circ\text{C}$), $V_S = +5\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$ to $V_S/2$, $G = 2$; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
V_{OL}	Output Voltage Swing, Low ⁽¹⁾	$+V_S = 5\text{V}$, $R_L = 10\text{k}\Omega$		5	20	mV
					30	mV
I_{SOURCE}	Output Current, Sourcing ⁽¹⁾	$V_{IN+} = 1\text{V}$, $V_{IN-} = 0\text{V}$, $+V_S = 15\text{V}$, $V_{OUT} = 2\text{V}$	20	40		mA
			20			
I_{SINK}	Output Current, Sinking ⁽¹⁾	$V_{IN+} = 0\text{V}$, $V_{IN-} = 1\text{V}$, $+V_S = 15\text{V}$, $V_{OUT} = 2\text{V}$	10	15		mA
			5			
		$V_{IN+} = 0\text{V}$, $V_{IN-} = 1\text{V}$, $+V_S = 15\text{V}$, $V_{OUT} = 0.2\text{V}$	12	50		μA
I_{SC}	Short Circuit Output Current ⁽¹⁾	$+V_S = 15\text{V}$		40	60	mA

Notes:

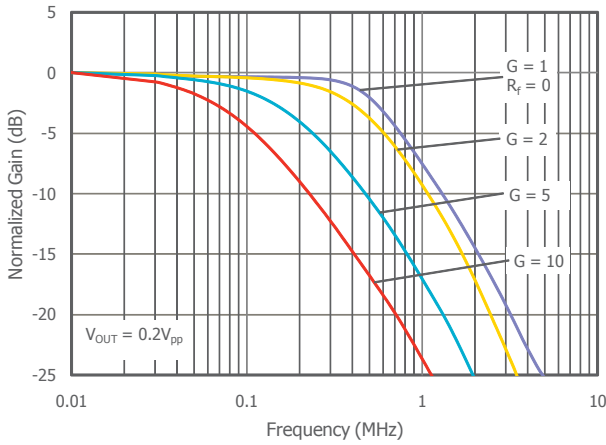
- 100% tested at 25°C . (Limits over the full temperature range are guaranteed by design.)
- The input common mode voltage of either input signal voltage should be kept $> 0.3\text{V}$ at 25°C . The upper end of the common-mode voltage range is $+V_S - 1.5\text{V}$ at 25°C , but either or both inputs can go to $+36\text{V}$ without damages, independent of the magnitude of V_S .



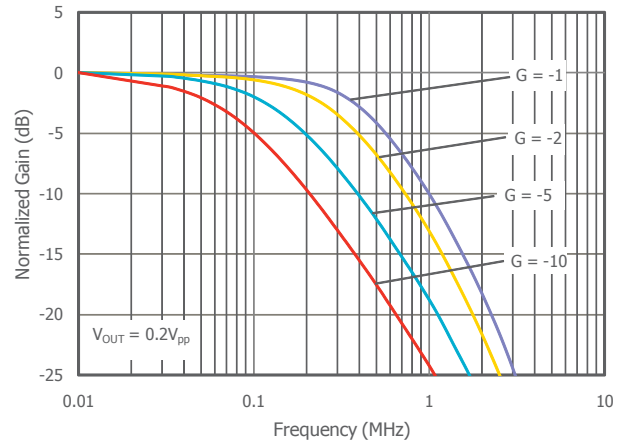
Typical Performance Characteristics

$T_A = 25^\circ\text{C}$, $+V_S = 30\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$, $G = 2$; unless otherwise noted.

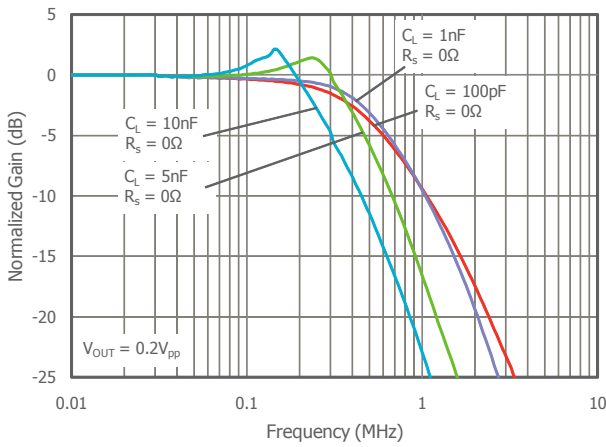
Non-Inverting Frequency Response



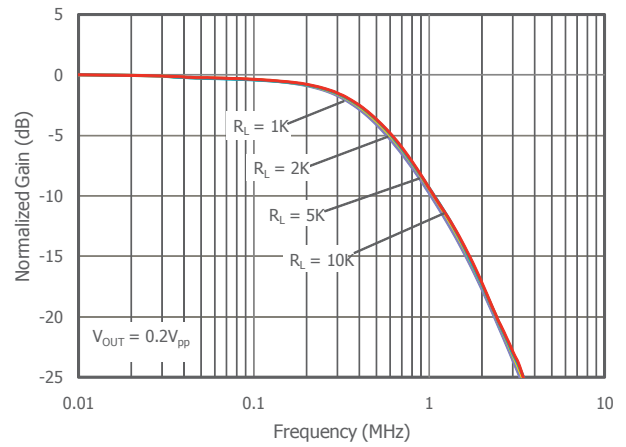
Inverting Frequency Response



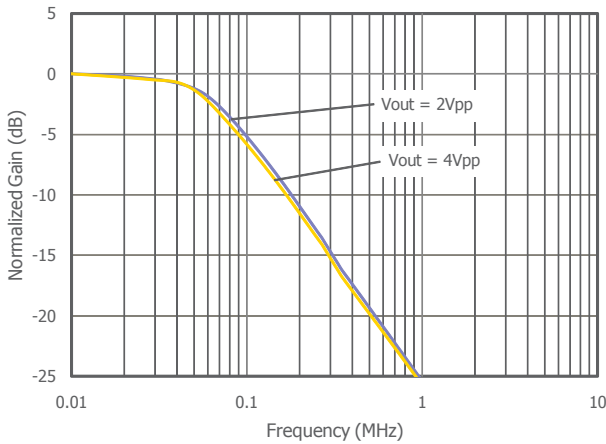
Frequency Response vs. C_L



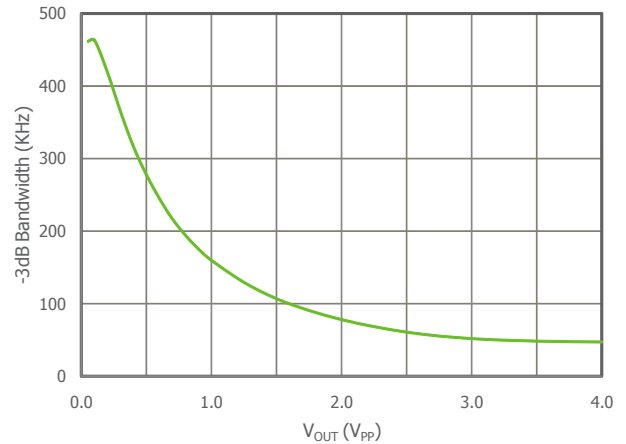
Frequency Response vs. R_L



Frequency Response vs. V_{OUT}



-3dB Bandwidth vs. V_{OUT}

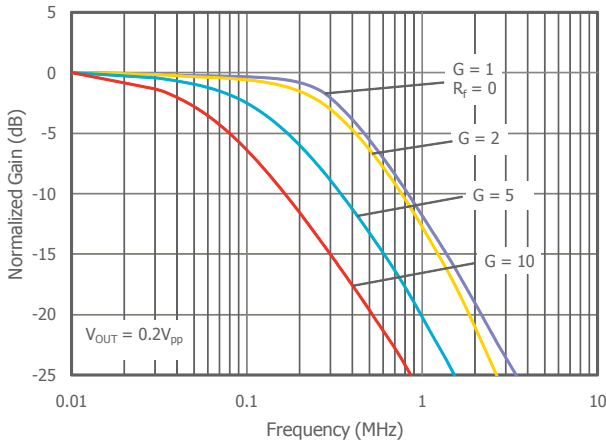




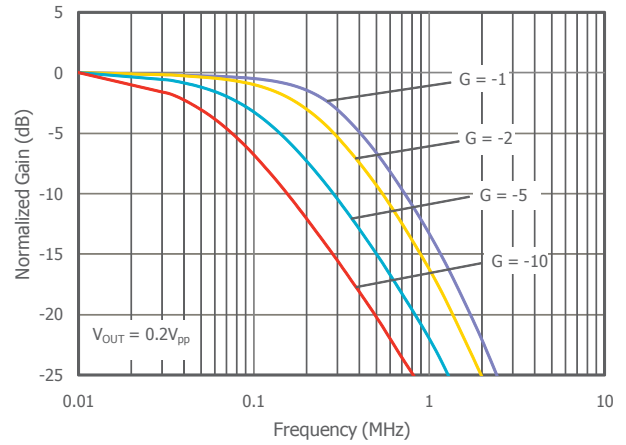
Typical Performance Characteristics

$T_A = 25^\circ\text{C}$, $+V_S = 30\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$, $G = 2$; unless otherwise noted.

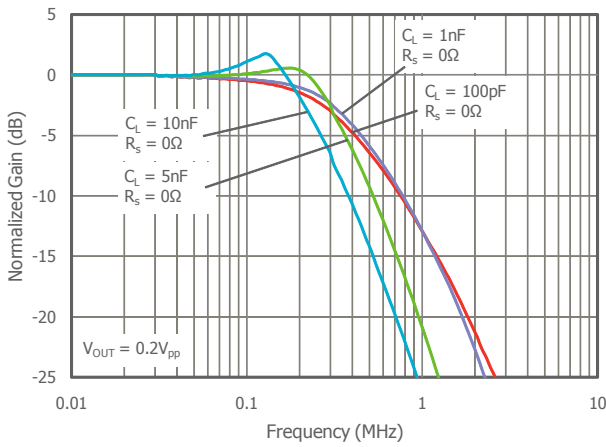
Non-Inverting Frequency Response at $V_S = 5\text{V}$



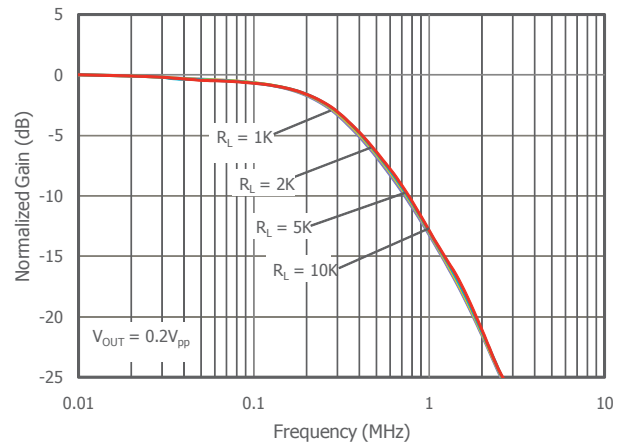
Inverting Frequency Response at $V_S = 5\text{V}$



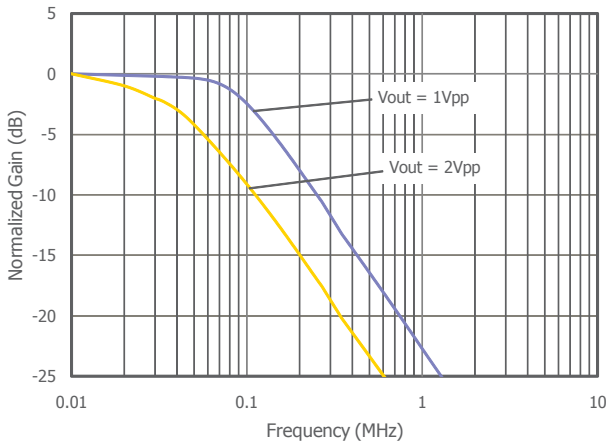
Frequency Response vs. C_L at $V_S = 5\text{V}$



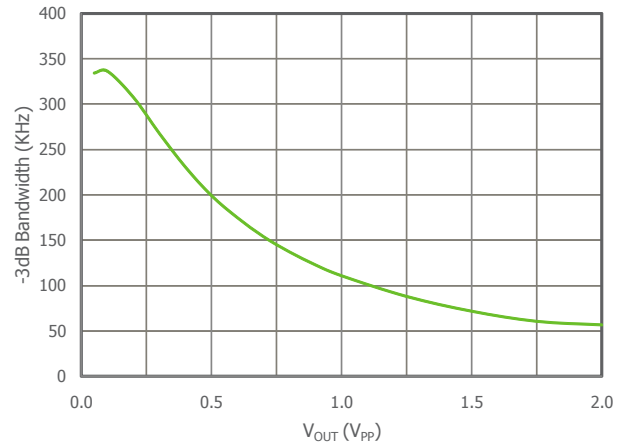
Frequency Response vs. R_L at $V_S = 5\text{V}$



Frequency Response vs. V_{OUT} at $V_S = 5\text{V}$



-3dB Bandwidth vs. V_{OUT} at $V_S = 5\text{V}$

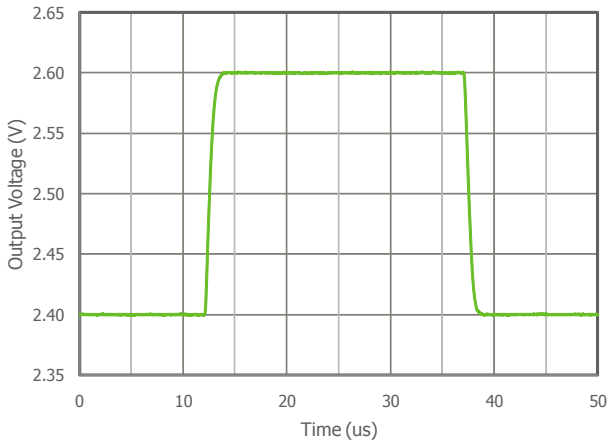




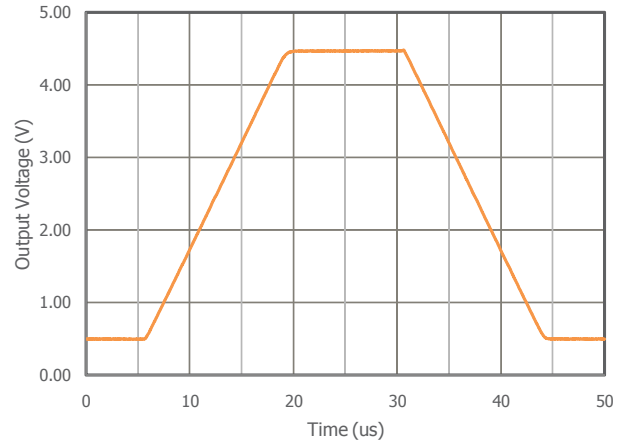
Typical Performance Characteristics - Continued

$T_A = 25^\circ\text{C}$, $+V_S = 30\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$, $G = 2$; unless otherwise noted.

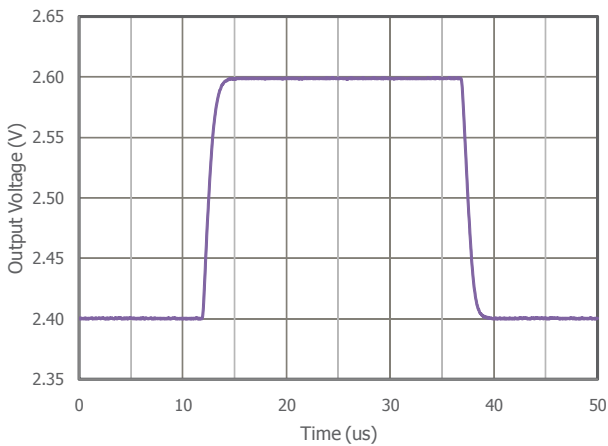
Small Signal Pulse Response



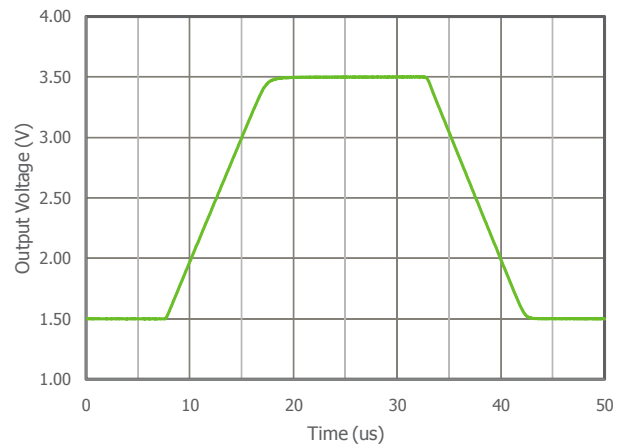
Large Signal Pulse Response



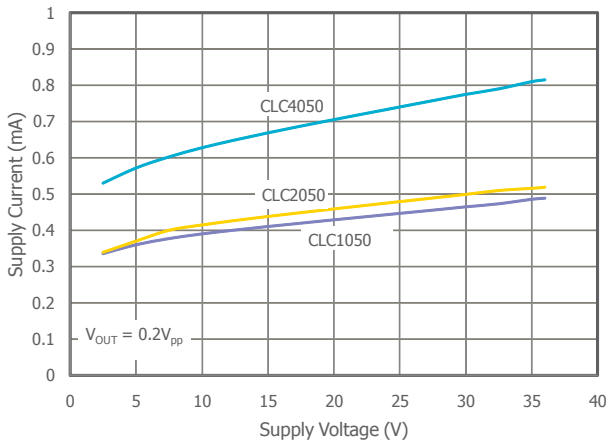
Small Signal Pulse Response at $V_S = 5\text{V}$



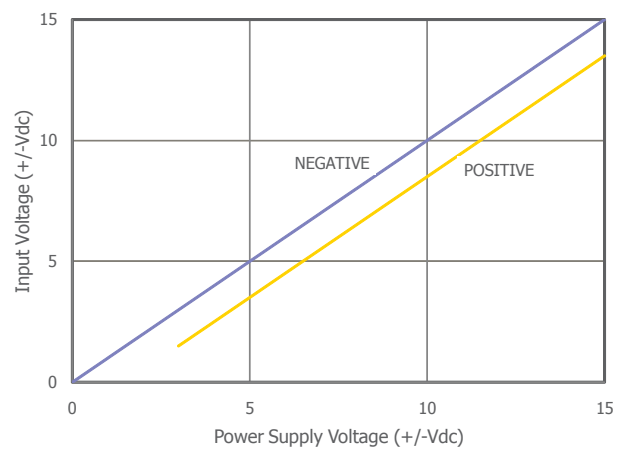
Large Signal Pulse Response at $V_S = 5\text{V}$



Supply Current vs. Supply Voltage



Input Voltage Range vs. Power Supply

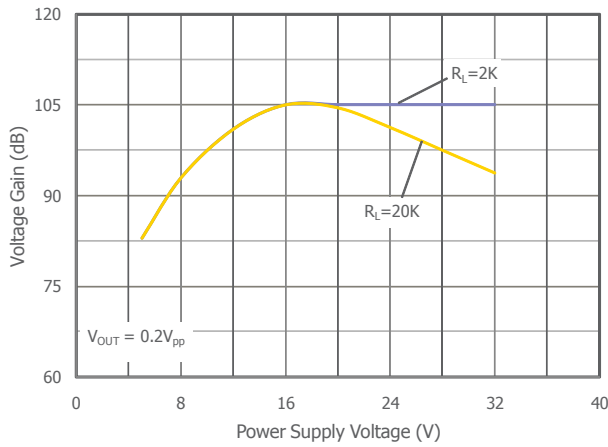




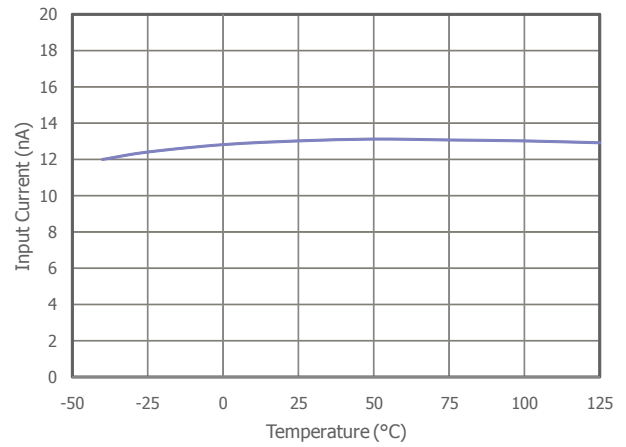
Typical Performance Characteristics - Continued

$T_A = 25^\circ\text{C}$, $+V_S = 30\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$, $G = 2$; unless otherwise noted.

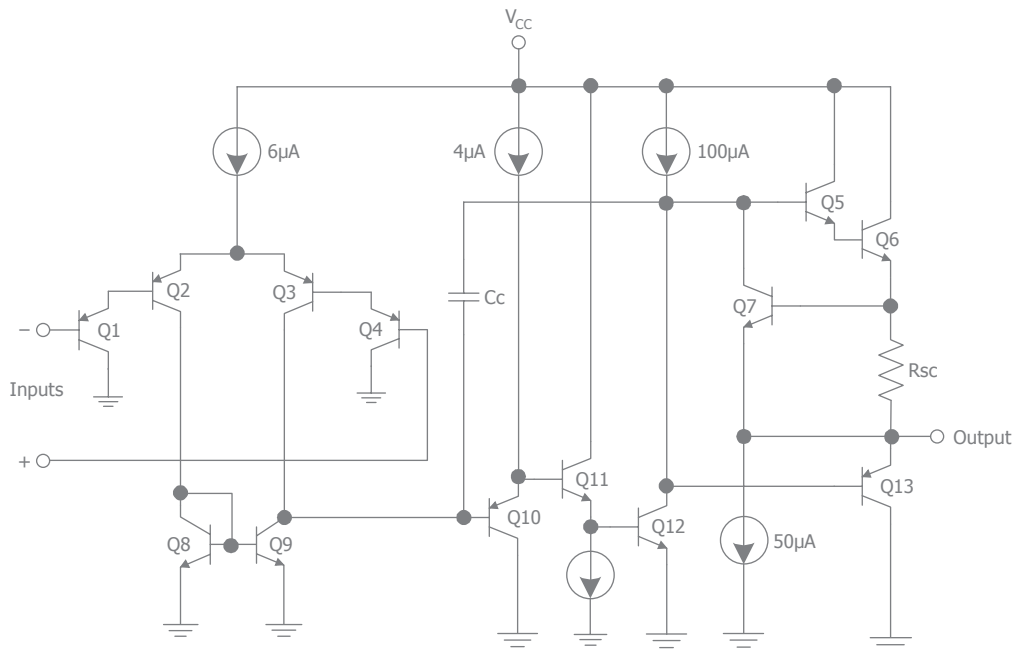
Voltage Gain vs. Supply Voltage



Input Current vs. Temperature



Functional Block Diagram





Application Information

Basic Operation

Figures 1, 2, and 3 illustrate typical circuit configurations for non-inverting, inverting, and unity gain topologies for dual supply applications. They show the recommended bypass capacitor values and overall closed loop gain equations.

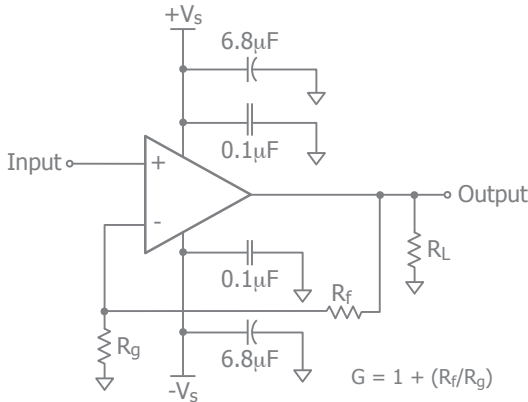


Figure 1. Typical Non-Inverting Gain Circuit

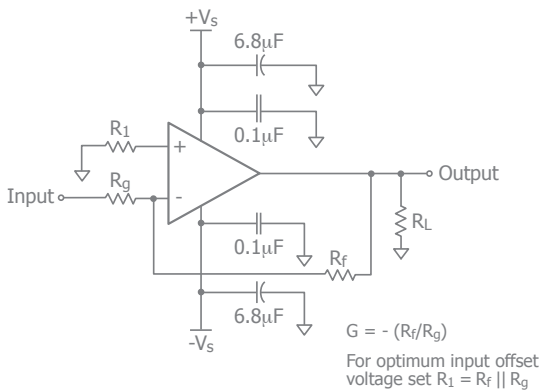


Figure 2. Typical Inverting Gain Circuit

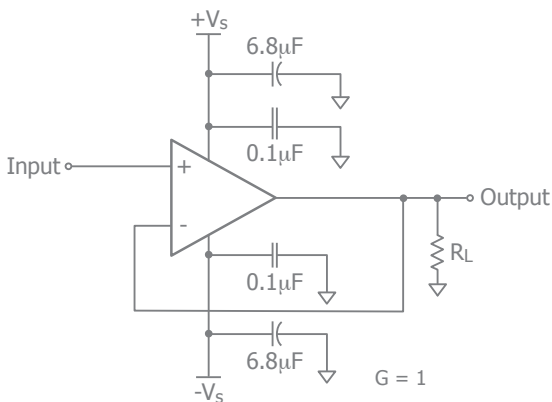


Figure 3. Unity Gain Circuit

Power Dissipation

Power dissipation should not be a factor when operating under the stated 2k ohm load condition. However, applications with low impedance, DC coupled loads should be analyzed to ensure that maximum allowed junction temperature is not exceeded. Guidelines listed below can be used to verify that the particular application will not cause the device to operate beyond its intended operating range.

Maximum power levels are set by the absolute maximum junction rating of 150°C. To calculate the junction temperature, the package thermal resistance value Θ_{JA} (Θ_{JA}) is used along with the total die power dissipation.

$$T_{\text{Junction}} = T_{\text{Ambient}} + (\Theta_{JA} \times P_D)$$

Where T_{Ambient} is the temperature of the working environment.

In order to determine P_D , the power dissipated in the load needs to be subtracted from the total power delivered by the supplies.

$$P_D = P_{\text{supply}} - P_{\text{load}}$$

Supply power is calculated by the standard power equation.

$$P_{\text{supply}} = V_{\text{supply}} \times I_{\text{RMS supply}}$$

$$V_{\text{supply}} = V_{S+} - V_{S-}$$

Power delivered to a purely resistive load is:

$$P_{\text{load}} = ((V_{\text{LOAD}})_{\text{RMS}}^2) / R_{\text{load eff}}$$

The effective load resistor ($R_{\text{load eff}}$) will need to include the effect of the feedback network. For instance,

$R_{\text{load eff}}$ in figure 3 would be calculated as:

$$R_L \parallel (R_f + R_g)$$

These measurements are basic and are relatively easy to perform with standard lab equipment. For design purposes however, prior knowledge of actual signal levels and load impedance is needed to determine the dissipated power. Here, P_D can be found from

$$P_D = P_{\text{Quiescent}} + P_{\text{Dynamic}} - P_{\text{Load}}$$

Quiescent power can be derived from the specified I_S values along with known supply voltage, V_{Supply} . Load power can be calculated as above with the desired signal amplitudes using:



$$(V_{LOAD})_{RMS} = V_{PEAK} / \sqrt{2}$$

$$(I_{LOAD})_{RMS} = (V_{LOAD})_{RMS} / R_{load\,eff}$$

The dynamic power is focused primarily within the output stage driving the load. This value can be calculated as:

$$P_{DYNAMIC} = (V_{S+} - V_{LOAD})_{RMS} \times (I_{LOAD})_{RMS}$$

Assuming the load is referenced in the middle of the power rails or $V_{supply}/2$.

Figure 4 shows the maximum safe power dissipation in the package vs. the ambient temperature for the packages available.

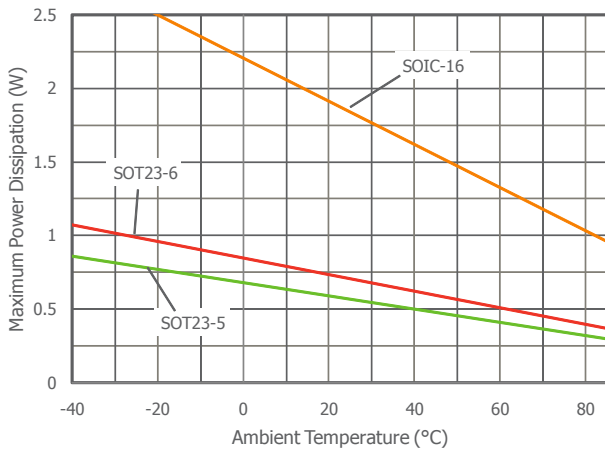


Figure 4. Maximum Power Derating

Driving Capacitive Loads

Increased phase delay at the output due to capacitive loading can cause ringing, peaking in the frequency response, and possible unstable behavior. Use a series resistance, R_S , between the amplifier and the load to help improve stability and settling performance. Refer to Figure 5.

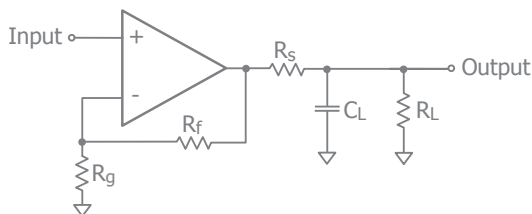


Figure 5. Addition of R_S for Driving Capacitive Loads

Table 1 provides the recommended R_S for various capacitive loads. The recommended R_S values result in ≤ 1 dB peaking in the frequency response. The Frequency Response vs. C_L plot, on page 6, illustrates the response of the CLCx050.

C_L (pF)	R_S (Ω)	-3dB BW (kHz)
1nF	0	485
5nF	0	390
10nF	0	260
100	0	440

Table 1: Recommended R_S vs. C_L

For a given load capacitance, adjust R_S to optimize the tradeoff between settling time and bandwidth. In general, reducing R_S will increase bandwidth at the expense of additional overshoot and ringing.

Overdrive Recovery

An overdrive condition is defined as the point when either one of the inputs or the output exceed their specified voltage range. Overdrive recovery is the time needed for the amplifier to return to its normal or linear operating point. The recovery time varies, based on whether the input or output is overdriven and by how much the range is exceeded. The CLCx050 will typically recover in less than 30ns from an overdrive condition. Figure 6 shows the CLC1050 in an overdriven condition.

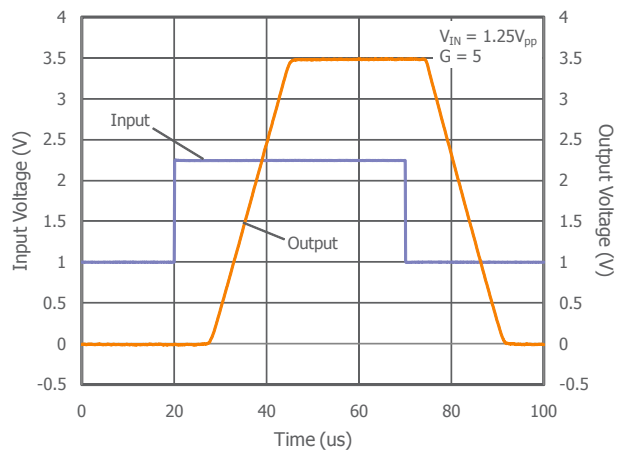


Figure 6. Overdrive Recovery



Layout Considerations

General layout and supply bypassing play major roles in high frequency performance. CADEKA has evaluation boards to use as a guide for high frequency layout and as an aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8 μ F and 0.1 μ F ceramic capacitors for power supply decoupling
- Place the 6.8 μ F capacitor within 0.75 inches of the power pin
- Place the 0.1 μ F capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts below for more information.

Evaluation Board Information

The following evaluation boards are available to aid in the testing and layout of these devices:

Evaluation Board	Products
CEB002	CLC1050
CEB006	CLC2050
CEB018	CLC4050

Evaluation Board Schematics

Evaluation board schematics and layouts are shown in Figures 7-14. These evaluation boards are built for dual-supply operation. Follow these steps to use the board in a single-supply application:

1. Short -Vs to ground.
2. Use C3 and C4, if the -Vs pin of the amplifier is not directly connected to the ground plane.

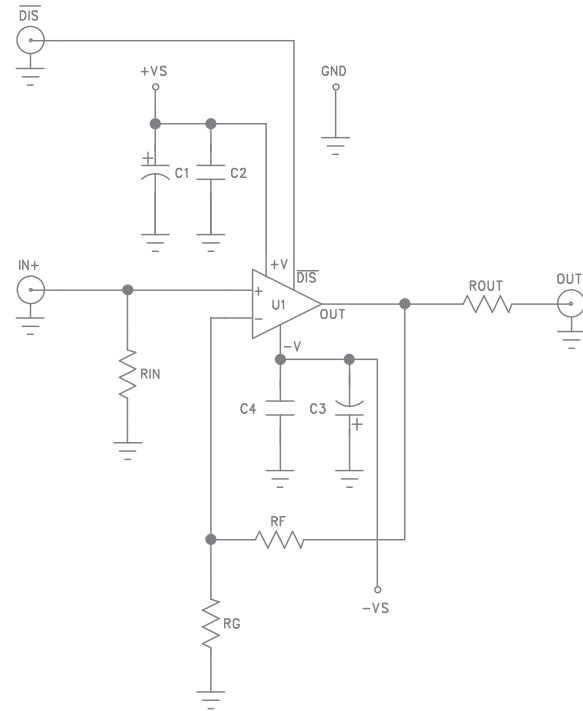


Figure 7. CEB002 Schematic

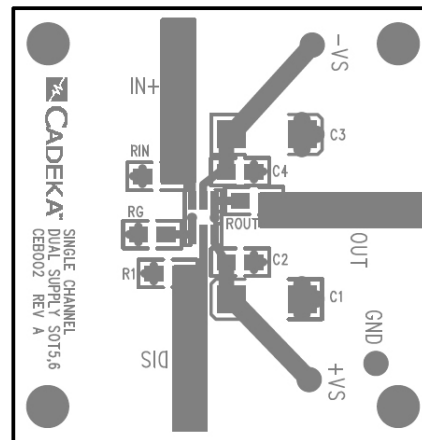


Figure 8. CEB002 Top View

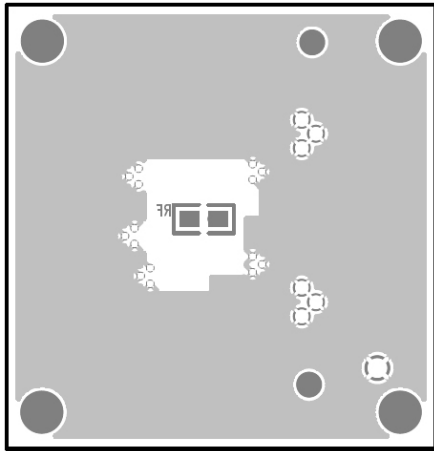


Figure 9. CEB002 Bottom View

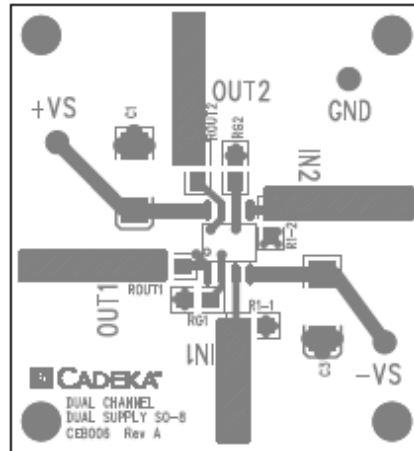


Figure 11. CEB006 Top View

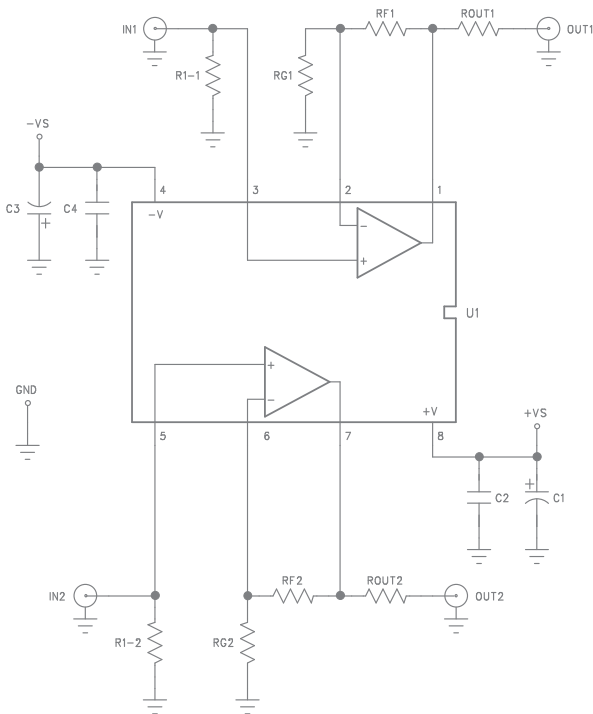


Figure 10. CEB006 Schematic

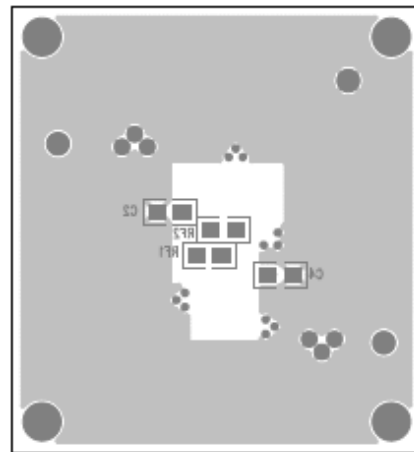


Figure 12. CEB006 Bottom View

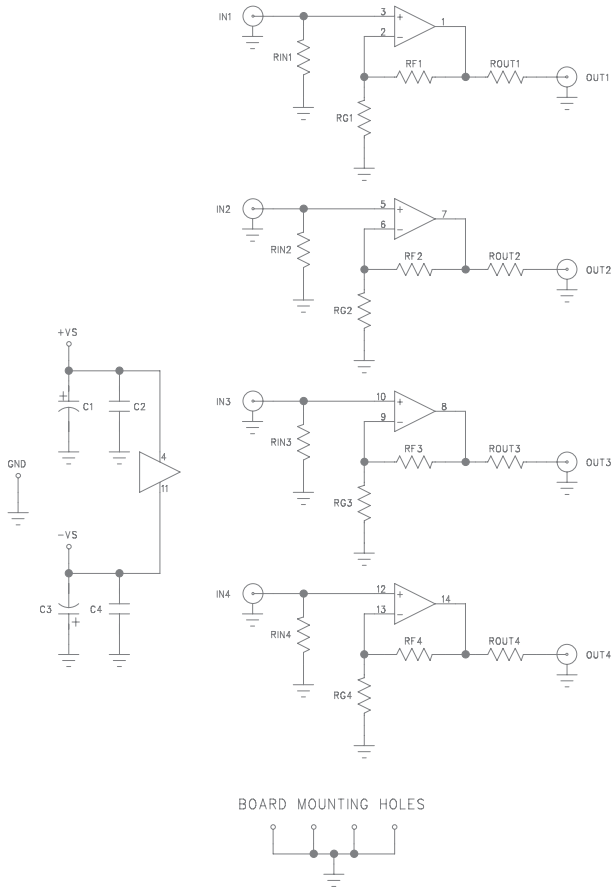


Figure 13. CEB018 Schematic

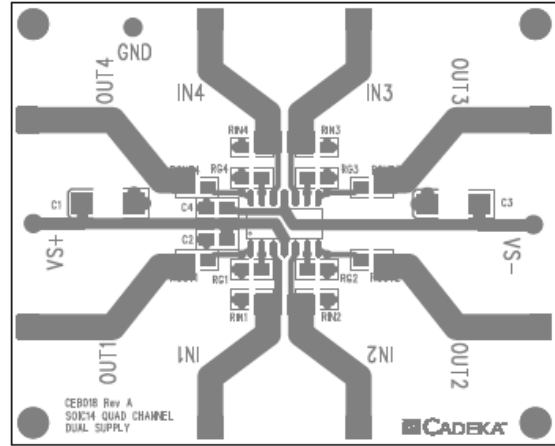


Figure 14 CEB018 Top View

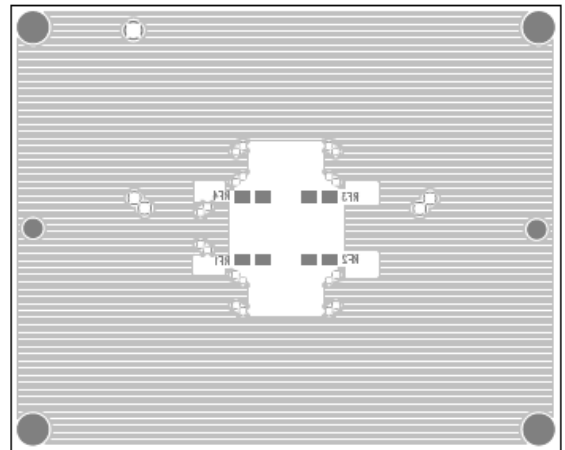


Figure 15. CEB018 Bottom View

Typical Applications

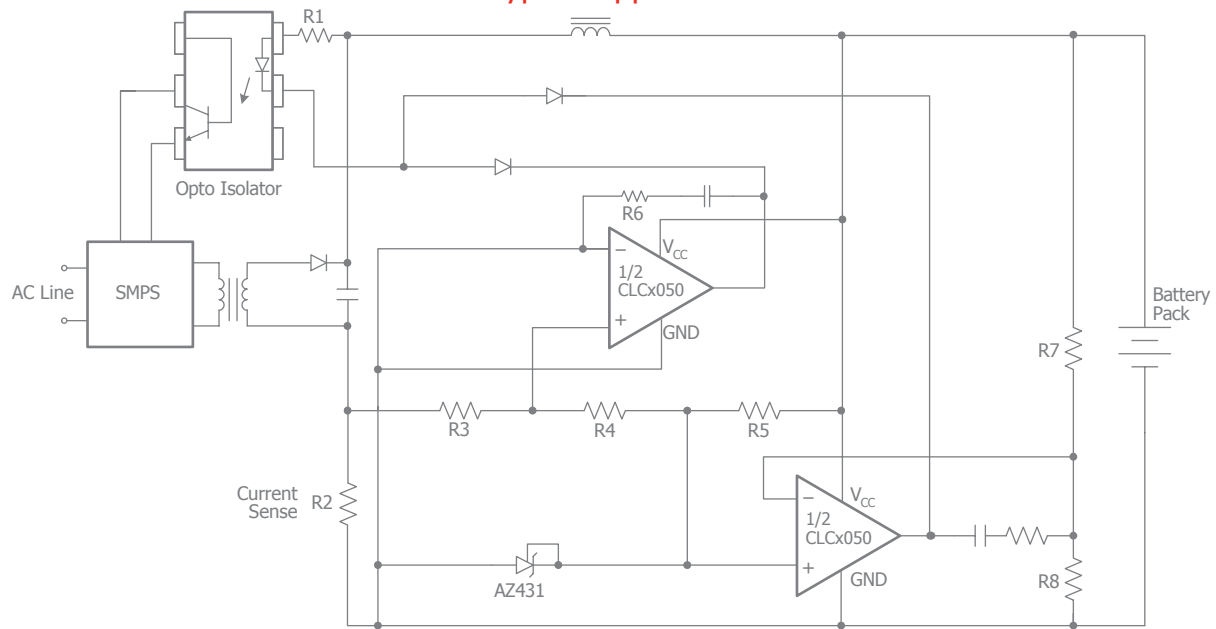


Figure 16. Battery Charger

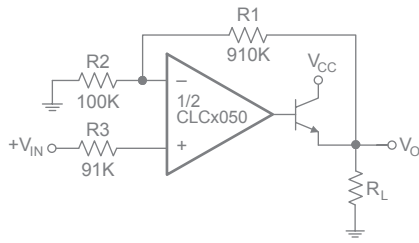


Figure 17. Power Amplifier

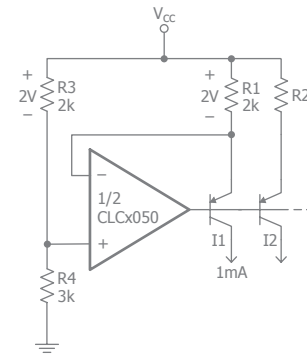


Figure 20. Fixed Current Sources

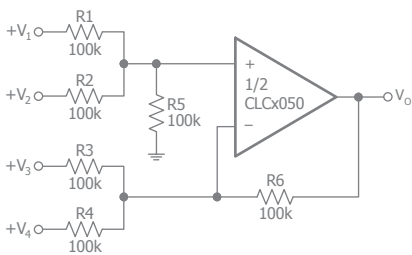


Figure 18. DC Summing Amplifier

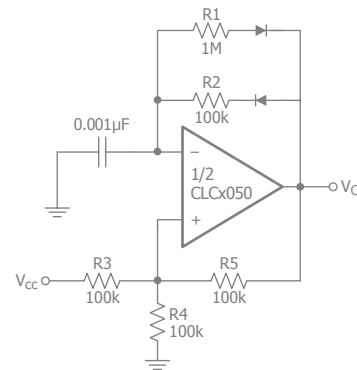


Figure 21. Pulse Generator

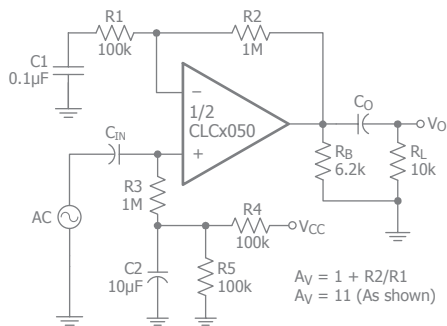


Figure 19. AC-Coupled Non-Inverting Amplifier

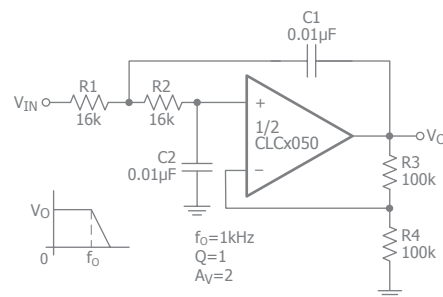
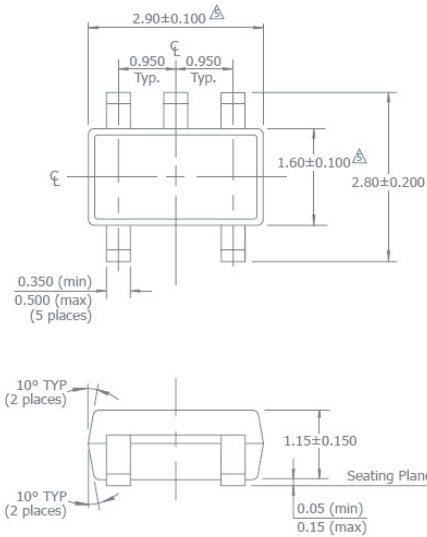


Figure 22. DC-Coupled Low-Pass Active Filter



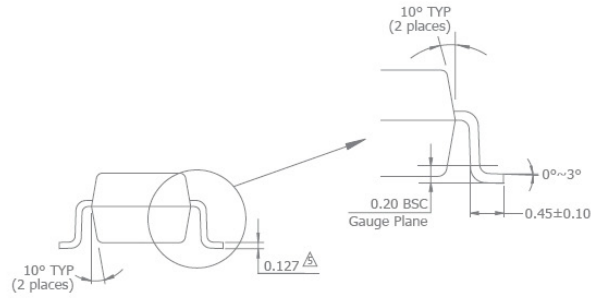
Mechanical Dimensions

SOT23-5 Package

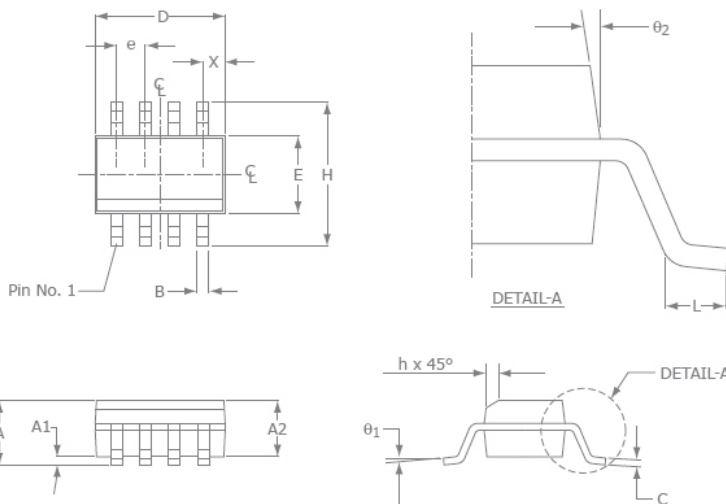


NOTES:

1. Dimensions and tolerances are as per ANSI Y14.5M-1982.
 2. Package surface to be matte finish VDI 11~13.
 3. Die is facing up for mold. Die is facing down for trim/form, ie. reverse trim/form.
 4. The footlength measuring is based on the gauge plane method.
- Δ Dimension are exclusive of mold flash and gate burr.
 Δ Dimension are exclusive of solder plating.



SOIC-8 Package



SOIC-8		
SYMBOL	MIN	MAX
A1	0.10	0.25
B	0.36	0.48
C	0.19	0.25
D	4.80	4.98
E	3.81	3.99
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.5
L	0.41	1.27
A	1.37	1.73
θ_1	0°	8°
X	0.55 ref	
θ_2	7° BSC	

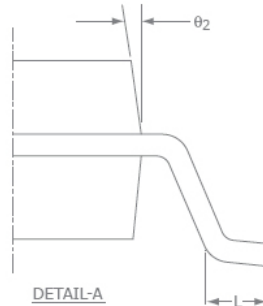
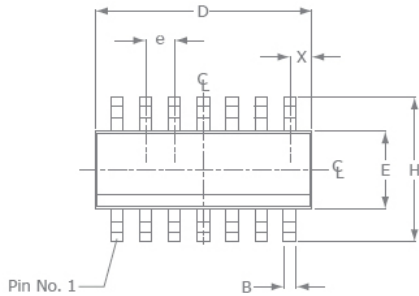
NOTE:

1. All dimensions are in millimeters.
2. Lead coplanarity should be 0 to 0.1mm (0.004") max.
3. Package surface finishing: VDI 24~27
4. All dimension excluding mold flashes.
5. The lead width, B to be determined at 0.1905mm from the lead tip.



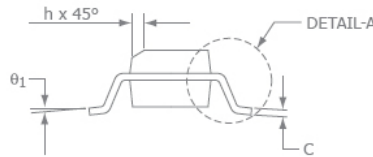
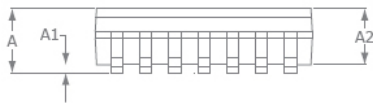
Mechanical Dimensions continued

SOIC-14 Package



DETAIL-A

SOIC-14		
SYMBOL	MIN	MAX
A1	0.10	0.25
B	0.36	0.48
C	0.19	0.25
D	8.56	8.74
E	3.84	3.99
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.5
L	0.41	1.27
A	1.37	1.73
θ_1	0°	8°
X	0.51 ref	
θ_2	7° BSC	



DETAIL-A

NOTE:

1. All dimensions are in millimeters.
2. Lead coplanarity should be 0 to 0.1mm (0.004") max
3. Package surface finishing: VDI 24~27
4. All dimension excluding mold flashes.
5. The lead width, B to be determined at 0.1905mm from the lead tip.

For additional information regarding our products, please visit CADEKA at: cadeka.com

CADEKA Headquarters Loveland, Colorado
 T: 970.663.5452
 T: 877.663.5452 (toll free)

CADEKA, the CADEKA logo design, COMLINEAR, the COMLINEAR logo design, and ARCTIC are trademarks or registered trademarks of CADEKA Microcircuits LLC. All other brand and product names may be trademarks of their respective companies.

CADEKA reserves the right to make changes to any products and services herein at any time without notice. CADEKA does not assume any responsibility or liability arising out of the application or use of any product or service described herein, except as expressly agreed to in writing by CADEKA; nor does the purchase, lease, or use of a product or service from CADEKA convey a license under any patent rights, copyrights, trademark rights, or any other of the intellectual property rights of CADEKA or of third parties.

Copyright ©2007-2009 by CADEKA Microcircuits LLC. All rights reserved.



Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9